NSN 5961-00-826-0799

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Inclosure Material:	
Metal	
Overall Length:	
0.260 inches	
Overall Diameter:	
0.370 inches	
Internal Configuration	n:
Junction contact	
Electrode Internally-	electrically Connected To Case:
Base	
Internal Junction Cor	nfiguration:
Npn	
Mounting Method:	
Terminal	
Terminal Circle Diam	eter:
0.200 inches	
Features Provided:	
Hermetically sealed ca	ise
Semiconductor Mate	rial:
Germanium	
Voltage Rating In Vol	ts Per Characteristic:
25.0 breakdown voltag	ge, collector-to-base, emitter open and 25.0 breakdown voltage, emitter-to-base, collector oper
Current Rating Per C	haracteristic:
300.00 milliamperes so	ource cutoff current and 10.00 milliamperes source cutoff current blank
Power Rating Per Ch	aracteristic:
150.0 milliwatts small-s	signal input power, common-collector
Maximum Operating	Tempurature Per Measurement Point:
100.0 degrees celsius	junction
Terminal Type And Q	luantity:
3 uninsulated wire lead	t de la construcción de la const
Specification Data:	
80131-release2918 pro	ofessional/industrial association specification
Shelf Life:	
N/a	
Unit Of Measure:	
Demilitarization:	
No	
Fiig:	
A110a0	